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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/700,466	11/05/2003	Tadahiro Ohmi	108390-00056	8803	
4372 75	590 04/06/2006		EXAM	EXAMINER	
ARENT FOX PLLC 1050 CONNECTICUT AVENUE, N.W.			TRAN, T	TRAN, THIEN F	
SUITE 400			ART UNIT	PAPER NUMBER	
WASHINGTO	, DC 20036		2811		
			DATE MAILED: 04/06/200	6	

Please find below and/or attached an Office communication concerning this application or proceeding.

			<u> </u>
	Application No.	Applicant(s)	
	10/700,466	OHMI, TADAHIRO	
Office Action Summary	Examiner	Art Unit	
	Thien F. Tran	2811	· _
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with	h the correspondence address	
 A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING ID. Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). 	DATE OF THIS COMMUNIC. .136(a). In no event, however, may a rep d will apply and will expire SIX (6) MONT te, cause the application to become ABA	ATION. ply be timely filed "HS from the mailing date of this communication in the mailing date of the mailing date of the mailing date of this communication in the mailing date of the	
Status			
1) Responsive to communication(s) filed on 21 A	March 2006.		
	is action is non-final.		
3) Since this application is in condition for allowa	ance except for formal matte	rs, prosecution as to the merits i	is
closed in accordance with the practice under	Ex parte Quayle, 1935 C.D.	11, 453 O.G. 213.	
Disposition of Claims			
4)⊠ Claim(s) <u>8-12 and 14-16</u> is/are pending in the	application.		
4a) Of the above claim(s) <u>8-12,14 and 15</u> is/ar	• •	tion.	
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>16</u> is/are rejected.		•	
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/o	or election requirement.		
Application Papers			
9) The specification is objected to by the Examine	er.		
10) The drawing(s) filed on is/are: a) acc		v the Examiner.	
Applicant may not request that any objection to the			
Replacement drawing sheet(s) including the correct	•	, ,	(d).
11) The oath or declaration is objected to by the E	· · · · · · · · · · · · · · · · · · ·	•	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. § 1	119(a)-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ None of:		· / · / · /	Î
1. Certified copies of the priority document	ts have been received.		
2. Certified copies of the priority document		plication No:	
3. Copies of the certified copies of the price	ority documents have been re	eceived in this National Stage	
application from the International Burea	ıu (PCT Rule 17.2(a)).		
* See the attached detailed Office action for a list	t of the certified copies not re	eceived.	
Attachment(s)			
Notice of References Cited (PTO-892)	4) Interview Su	mmary (PTO-413)	
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Mail Date ormal Patent Application (PTO-152)	
 Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date) 5) Notice of Info 6) Other:		

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DETAILED ACTION

Claim Rejections - 35 USC § 112

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

Claim 16 is rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. The recitation "a threshold voltage of said MOS transistor is substantially equal to that of an MOS transistor having a silicon oxide film without Kr" in claim 16 (new claim filed in the preliminary amendment) sets for a structure not supported by the specification. The specification does not disclose a threshold voltage of said MOS transistor being substantially equal to that of an MOS transistor having a silicon oxide film without Kr. Applicant is requested to point out exactly wherein the specification that discloses a threshold voltage of said MOS transistor being substantially equal to that of an MOS transistor having a silicon oxide film without Kr.

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 16 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant

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regards as the invention. The limitation "a threshold voltage of said MOS transistor is substantially equal to that of an MOS transistor having a silicon oxide film without Kr" does not appear in the specification. The specification does not define and provide a standard for determining what is encompassed by a threshold voltage of said MOS transistor substantially equal to that of an MOS transistor having a silicon oxide film without Kr. The drawings fail to describe a threshold voltage of said MOS transistor being substantially equal to that of an MOS transistor having a silicon oxide film without Kr. Consequently, the claimed subject matter is indefinite.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 16, insofar as in compliance with 35 USC 112, is rejected under 35 U.S.C. 102(b) as being anticipated by Jacobs et al. (US 4,027,320).

Jacobs et al. discloses the claimed MOS transistor (see the drawing) having a silicon semiconductor portion (1) between source and drain regions (2, 3) for its channel region, a silicon oxide film (4) formed on said silicon semiconductor portion and a gate electrode (5) formed on said silicon oxide film, wherein said silicon oxide film contains Kr. Jacobs et al. has the same silicon oxide film containing Kr as claimed; therefore, it is inherent that a threshold voltage of the MOS transistor is substantially equal to that of an MOS transistor having a silicon oxide film without Kr. It is noted that he claimed

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characteristic or function is not clearly defined in the specification. Therefore, the examiner considers the claimed function as inherent or obvious to a person having ordinary skill in the art.

Conclusion ·

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thien F. Tran whose telephone number is (571) 272-1665. The examiner can normally be reached on 8:30AM - 5:00PM Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

π April 2, 2006

Thien Tran
Primary Examiner